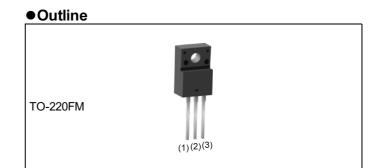
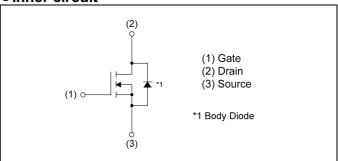


Nch 600V 30A Power MOSFET

V <sub>DSS</sub>	600V
R <sub>DS(on)</sub> (Max.)	0.130Ω
Ι <sub>D</sub>	±30A
P <sub>D</sub>	86W



#### Inner circuit



#### Packaging specifications

Code	Packing
C7 G	Tube
C7	Tube*
- (Blank)	Bulk*

\*Package dimensions are different

#### • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source voltage		V <sub>DSS</sub>	600	V
Continuous drain current		I <sub>D</sub> *1	±30	А
Pulsed drain current	<sup>*2</sup>	±80	А	
Cata Cauraa valtaria	static	- V <sub>GSS</sub>	±20	V
Gate - Source voltage	AC(f>1Hz)		±30	V
Avalanche current, single pulse		I <sub>AS</sub>	5.2	А
Avalanche energy, single pulse		$E_{AS}^{*3}$	636	mJ
Power dissipation ( $T_c = 25^{\circ}C$ )		PD	86	W
Junction temperature		Tj	150	°C
Operating junction and storage te	T <sub>stg</sub>	-55 to +150	°C	

#### Features

Application

Switching

- 1) Low on-resistance
- 2) Ultra fast switching
- 3) Parallel use is easy
- 4) Pb-free plating ; RoHS compliant

#### •Thermal resistance

Deremeter	Cymab al	Values			Linit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	$R_{thJC}^{*4}$	-	-	1.5	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub>	-	-	70	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# •Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter	Sumbol	Conditions	Values			- Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	600	-	-	V
		V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V				
Zero gate voltage drain current	I <sub>DSS</sub>	$T_j = 25^{\circ}C$	-	-	100	μA
		$T_j = 125^{\circ}C$	-	-	1000	
Gate - Source leakage current	I <sub>GSS</sub>	$I_{GSS}$ $V_{GS} = \pm 20V, V_{DS} = 0V$		-	±100	nA
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	3	-	5	V
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 14.5A				
Static drain - source on - state resistance	$R_{DS(on)}^{*5}$	$T_j = 25^{\circ}C$	-	0.115	0.130	Ω
		$T_j = 125^{\circ}C$	-	0.260	-	
Gate resistance	R <sub>G</sub>	f = 1MHz, open drain	-	2.1	-	Ω



## •Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	C: make al	Conditions		L lucit		
Parameter	Symbol			Тур.	Max.	Unit
Forward Transfer Admittance	Y <sub>fs</sub>  * <sup>5</sup>	<sup>5</sup> V <sub>DS</sub> = 10V, I <sub>D</sub> = 15A		20	-	S
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	2350	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	2000	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	70	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 300$ V, $V_{GS}$ = 10V	-	35	-	
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = 15A	-	65	-	20
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L \simeq 20\Omega$	-	100	-	ns
Fall time	t <sub>f</sub> *5	R <sub>G</sub> = 10Ω	-	50	-	

# • Gate charge characteristics (T<sub>a</sub> = 25°C)

Deremeter	Cumph of	Conditions	Values			L lucit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*5}$	V <sub>DD</sub> ≃ 300V	-	56	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 30A	-	18	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 10V	-	23	-	
Gate plateau voltage	V <sub>(plateau)</sub>	$V_{DD} \simeq 300$ V, I <sub>D</sub> = 30A	-	6.6	-	V

\*1 Limited only by maximum channel temperature allowed.

\*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

\*3 L $\doteqdot$ 50mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , STARTING T<sub>j</sub>=25°C

\*4 T<sub>C</sub>=25°C

\*5 Pulsed

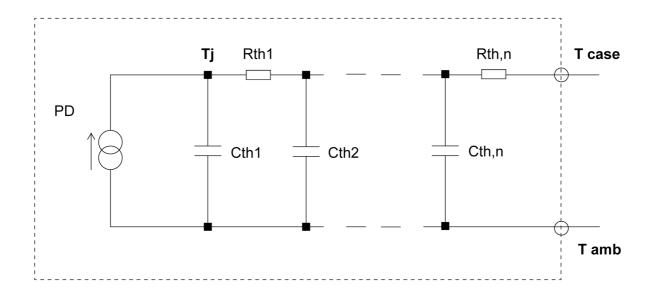


# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Sumbol	Conditions		Unit			
	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Continuous forward current	۱ <sub>S</sub> *1	T - 25°0	-	-	30	А	
Pulse forward current	ا <sub>SP</sub> *2	T <sub>C</sub> = 25°C	-	-	80	А	
Forward voltage	$V_{SD}^{*5}$	V <sub>GS</sub> = 0V, I <sub>S</sub> = 30A	-	-	1.5	V	
Reverse recovery time	t <sub>rr</sub> *5		-	517	-	ns	
Reverse recovery charge	Q <sub>rr</sub> *5	I <sub>S</sub> = 30A di/dt = 100A/µs	-	9.6	-	μC	
Peak reverse recovery current	۲ <sub>rrm</sub> *5		-	37	-	А	

# • Typical transient thermal characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R <sub>th1</sub>	0.0973		C <sub>th1</sub>	0.00375	
R <sub>th2</sub>	0.618	K/W	C <sub>th2</sub>	0.0519	Ws/K
R <sub>th3</sub>	2.14		 C <sub>th3</sub>	0.524	





#### • Electrical characteristic curves

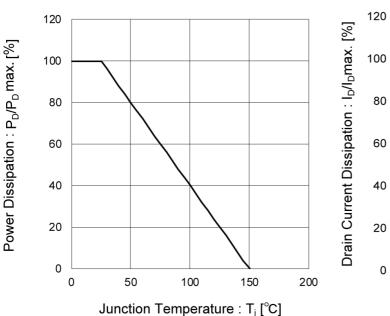
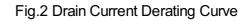


Fig.1 Power Dissipation Derating Curve



 $\begin{array}{c}
120\\
100\\
80\\
60\\
40\\
20\\
-25 0 25 50 75 100 125 150\\
Junction Temperature : T_i [°C]
\end{array}$ 

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

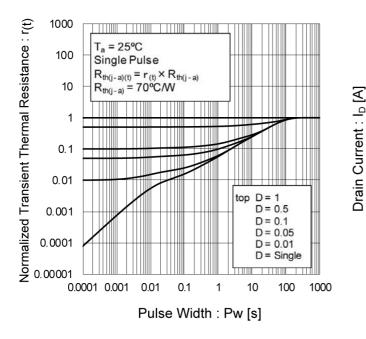
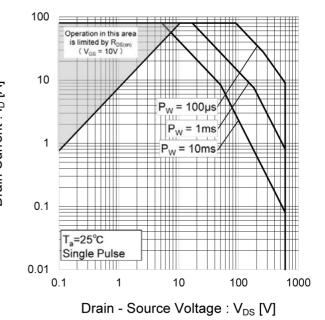


Fig.4 Maximum Safe Operating Area





### • Electrical characteristic curves

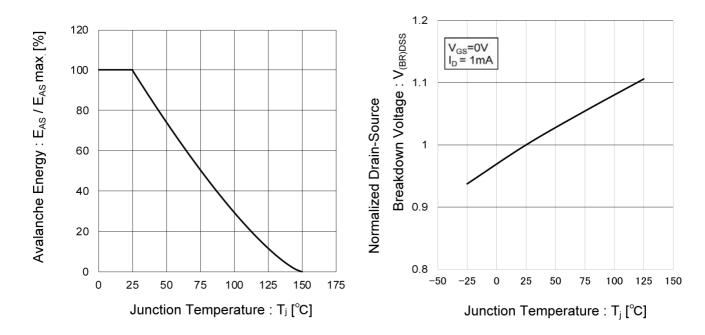


Fig.5 Avalanche Energy Derating Curve

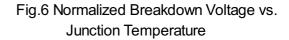


Fig.7 Typical Output Characteristics(I)

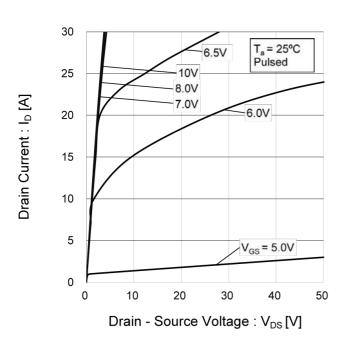


Fig.8 Typical Output Characteristics(II)

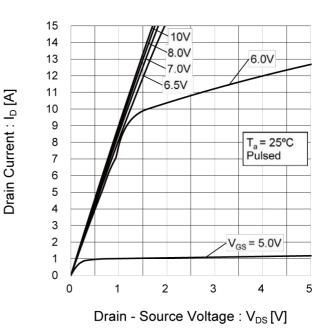




Fig.9 Typical Transfer Characteristics

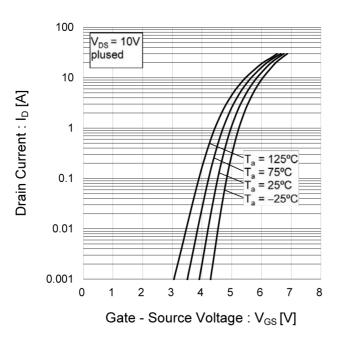


Fig.10Gate Threshold Voltage vs. Junction Temperature

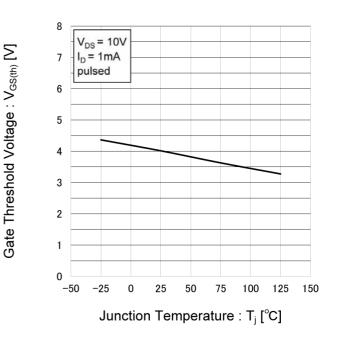
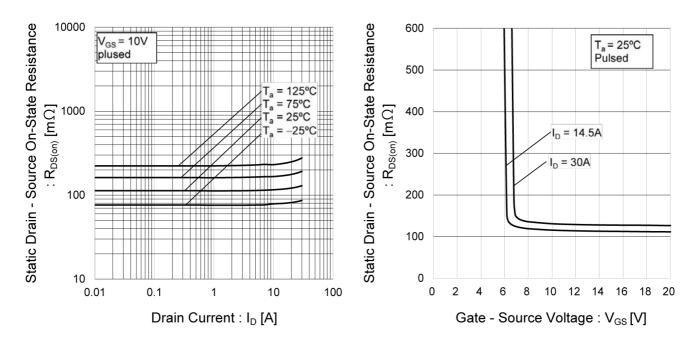


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage





#### •Electrical characteristic curves

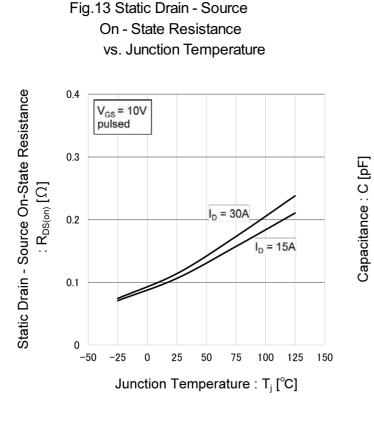


Fig.14 Typical Capacitance vs. Drain - Source Voltage

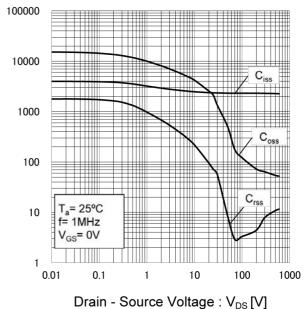


Fig.15 Switching Characteristics

Fig.16 Typical Gate Charge

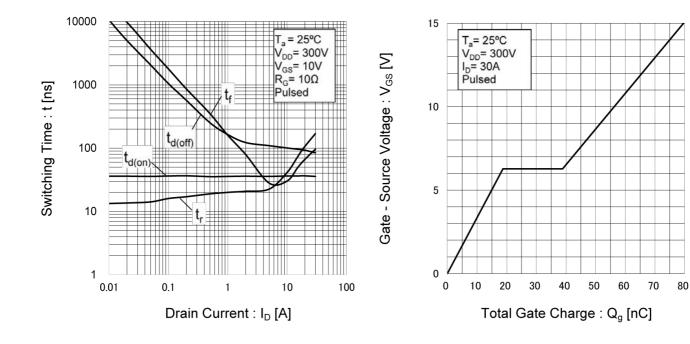




Fig.18 Reverse Recovery Time vs. Source Current

#### • Electrical characteristic curves

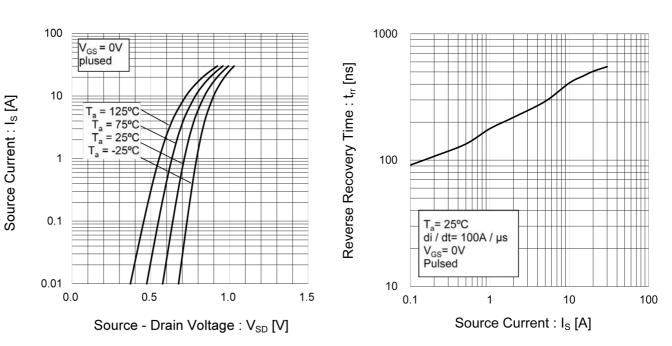


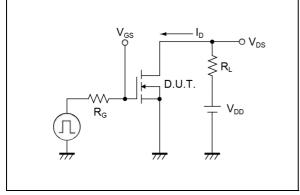
Fig.17 Source Current vs. Source - Drain Voltage



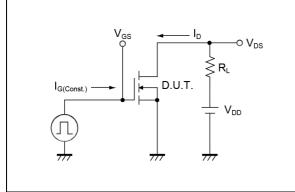


#### Measurement circuits

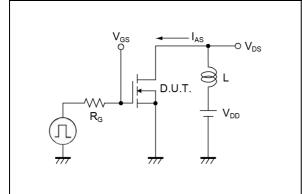
Fig.1-1 Switching Time Measurement Circuit



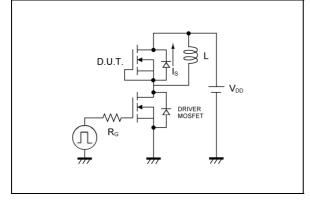
#### Fig.2-1 Gate Charge Measurement Circuit



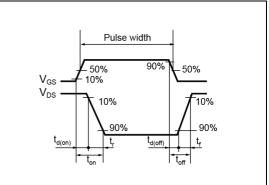
#### Fig.3-1 Avalanche Measurement Circuit



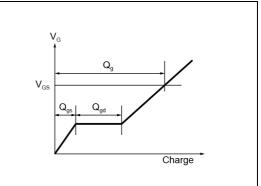
#### Fig.4-1 trr Measurement Circuit



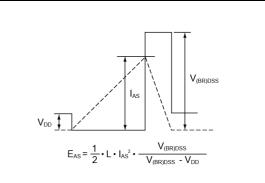
#### Fig.1-2 Switching Waveforms



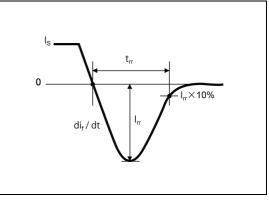
#### Fig.2-2 Gate Charge Waveform



#### Fig.3-2 Avalanche Waveform

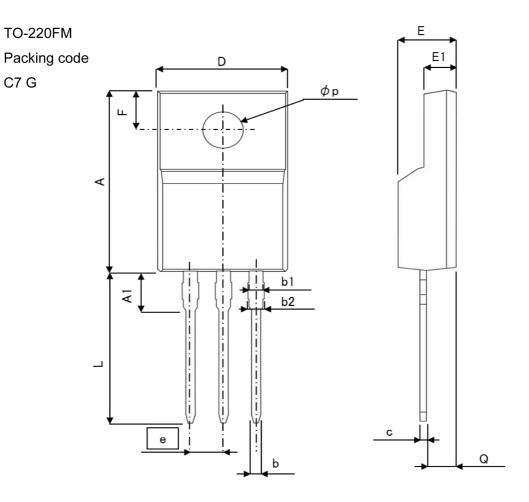


#### Fig.4-2 trr Waveform





### Dimensions

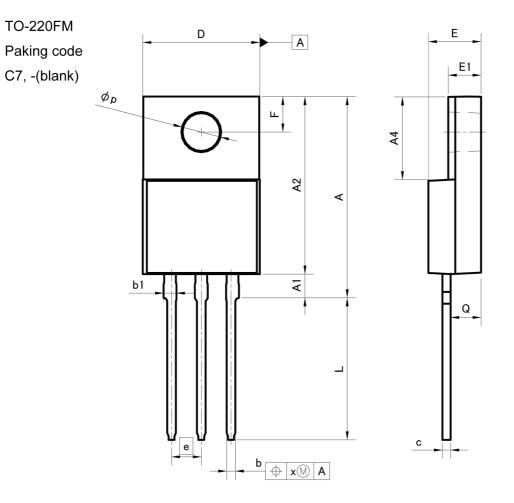


DIM	MILIM	ETERS	INC	HES	
	MIN MAX		MIN	MAX	
A	15.67	16.27	0.617	0.641	
A1	3.03	3.43	0.119	0.135	
b	0.70	0.95	0.028	0.037	
b1	1.00	1.40	0.039	0.055	
b2	1.10	1.50	0.043	0.059	
с	0.45	0.65	0.018	0.026	
D	9.90	10.30	0.390	0.406	
E	4.60	5.00	0.181	0.197	
E1	2.44	2.74	0.096	0.108	
е	2.	54	0.100		
F	3.10	3.50	0.122	0.138	
L	12.6	13.6	0.946	0.535	
р	2.98	3.38	0.117	0.133	
Q	2.25	3.25	0.089	0.128	

Dimension in mm/inches



#### Dimensions



DIM	MILIM	ETERS	INCH	IES
DIM	MIN	MAX	MIN	MAX
A	16.60	17.60	0.654	0.693
A1	1.80	2.20	0.071	0.087
A2	14.80	15.40	0.583	0.606
A4	6.80	7.20	0.268	0.283
b	0.70	0.90	0.028	0.035
b1	1.10	1.50	0.043	0.059
с	0.70	0.85	0.028	0.033
D	9.90	10.30	0.390	0.406
E	4.40	4.80	0.173	0.189
е	2.	54	0.100	
E1	2.70	3.00	0.106	0.118
F	2.80	3.20	0.110	0.126
L	11.50	12.50	0.453	0.492
р	3.00	3.40	0.118	0.134
Q	2.10	3.10	0.083	0.122
x	-	0.38	-	0.015

Dimension in mm/inches



# Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (<sup>Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications
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JÁPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ		CLASSⅢ	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
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  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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When disposing Products please dispose them properly using an authorized industry waste company.

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